

# **isc Silicon PNP Darlington Power Transistor**

### **BD896A**

#### **DESCRIPTION**

- · Collector-Emitter Breakdown Voltage-
  - : V<sub>(BR)CEO</sub>= -45V(Min)
- · High DC Current Gain
  - : h<sub>FE</sub>= 750(Min) @I<sub>C</sub>= -4A
- · Collector Power Dissipation-
- : Pc= 70W@ Tc= 25°C
- 8 A Continuous Collector Current
- Complement to Type BD895A
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



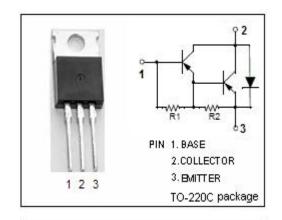
 Designed for use as complementary AF push-pull output stage applications

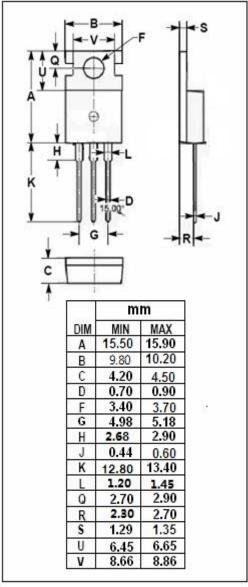
### ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

| SYMBOL           | PARAMETER  | VALUE   | UNIT       |  |
|------------------|--|---------|------------|--|
| V <sub>CBO</sub> | Collector-Base Voltage                               | -45     | V          |  |
| V <sub>CEO</sub> | Collector-Emitter Voltage                            | -45     | V          |  |
| V <sub>EBO</sub> | Emitter-Base Voltage                                 | -5      | V          |  |
| Ic               | Collector Current-Continuous                         | -8      | Α          |  |
| I <sub>B</sub>   | Base Current-Continuous                              | -0.3    | Α          |  |
| Pc               | Collector Power Dissipation @ T <sub>a</sub> =25℃    | 2       | 10/        |  |
|                  | Collector Power Dissipation<br>@ T <sub>C</sub> =25℃ | 70      | W          |  |
| TJ               | Junction Temperature                                 | 150     | $^{\circ}$ |  |
| T <sub>stg</sub> | Storage Temperature Range                            | -65~150 | $^{\circ}$ |  |

#### THERMAL CHARACTERISTICS

| SYMBOL              | PARAMETER   | MAX  | UNIT |
|---------------------|---|------|------|
| R <sub>th j-c</sub> | Thermal Resistance,Junction to Case                         | 1.79 | °C/W |
| R <sub>th j-a</sub> | R <sub>th j-a</sub> Thermal Resistance, Junction to Ambient |      | °C/W |







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#### **ELECTRICAL CHARACTERISTICS**

T<sub>C</sub>=25℃ unless otherwise specified

| SYMBOL               | PARAMETER                            | CONDITIONS   | MIN | TYP. | MAX          | UNIT |
|----------------------|--------------------------------------|--|-----|------|--------------|------|
| V <sub>(BR)CEO</sub> | Collector-Emitter Breakdown Voltage  | I <sub>C</sub> = -50mA; I <sub>B</sub> = 0                         | -45 |      |              | V    |
| V <sub>CE(sat)</sub> | Collector-Emitter Saturation Voltage | I <sub>C</sub> = -4A; I <sub>B</sub> = -16mA                       |     |      | -2.5         | V    |
| V <sub>BE(on)</sub>  | Base-Emitter On Voltage              | I <sub>C</sub> = -4A ; V <sub>CE</sub> = -3V                       |     |      | -2.5         | V    |
| І <sub>сво</sub>     | Collector Cutoff Current             | V <sub>CB</sub> = -45V; I <sub>E</sub> = 0                         |     |      | -0.2<br>-2.0 | mA   |
|                      |                                      | V <sub>CB</sub> = -45V; I <sub>E</sub> = 0; T <sub>C</sub> = 100 ℃ |     |      |              | ША   |
| I <sub>CEO</sub>     | Collector Cutoff Current             | V <sub>CE</sub> = -30V; I <sub>B</sub> = 0                         |     |      | -0.5         | mA   |
| I <sub>EBO</sub>     | Emitter Cutoff Current               | V <sub>EB</sub> = -5V; I <sub>C</sub> = 0                          |     |      | -2           | mA   |
| h <sub>FE</sub>      | DC Current Gain                      | I <sub>C</sub> = -4A; V <sub>CE</sub> = -3V                        | 750 |      |              |      |

#### **NOTICE:**

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